

## <u>PATENT</u>

Pesponse 5/21/03 Ahm H

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT:

SCHAUER ET AL 1 PCT

SERIAL NO.:

09/890,656

EXAMINER: T.F.TRAN

FILED:

AUGUST 2, 2001

GROUP: 2811

TITLE:

SEMICONDUCTOR WAFER COMPRISING A THIN EPITAX FAL

SILICON LAYER AND METHOD FOR PRODUCING THE SAME

RESPONSE TO A FIRST OFFICE ACTION

ATTN: MAIL STOP FEE AMENDMENT

Assistant Commissioner for Patents

P.O.BOX 1450

Alexandria, VA 22313-1450

Dear Sir:

This is in response to the First Office Action dated January 13, 2003, with the time for reply having been extended for one month, from <u>APRIL 13, 2003</u>, until <u>MAY 13, 2003</u>.

The Remarks begin on Page 2.